Low Power Single Voltage Comparator

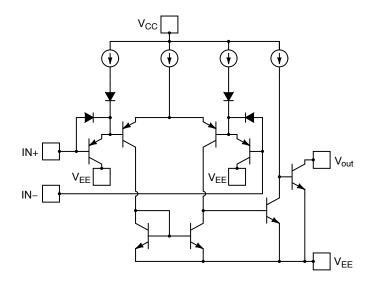
Description

The TS391 is an open collector, low–power voltage comparator designed specifically to operate from a single supply over a wide range of voltages. Operation from split power supplies is also possible.

This comparator also has a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Features

- Wide Single Supply Voltage Range or Dual Supplies
- Low Supply Current (0.5 mA) Independent of Supply Voltage (1 mW/Comparator at +5 V)
- Low Input Bias Current: 25 nA TYP
- Low Input Offset Current: ±5 nA TYP
- Low Input Offset Voltage: ±1 mV TYP
- Input Common Mode Voltage Range includes Ground
- Low Output Saturation Voltage: 250 mV TYP at $I_O = 4$ mA
- Differential Input Voltage Range Equal to the Supply Voltage
- TTL, DTL, ECL, CMOS Compatible Devices
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable





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TSOP-5 SN SUFFIX CASE 483

MARKING DIAGRAM



Analog

391 = Specific Device Code A = Assembly Location

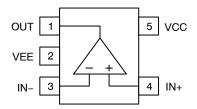
Y = Year

N = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping [†]
TS391SN2T1G	TSOP-5 (Pb-Free)	3000 / Tape & Reel
NCV391SN2T1G*	TSOP-5 (Pb-Free)	3000 / Tape & Reel

- †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
- * NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

Table 1. ABSOLUTE MAXIMUM RATINGS (Over operating free-air temperature, unless otherwise stated)

Parameter	Symbol	Limit	Unit	
Supply Voltage (V _{CC} - V _{EE})	V _S	36	V	
INPUT AND OUTPUT PINS				
Input Voltage	V _{IN}	±36	V	
Differential Input Voltage	V _{ID}	-0.3 to 36	V	
Output Short Circuit Current (Note 1)	I _{sc}	20	mA	
TEMPERATURE				
Storage Temperature	T _{STG}	-65 to +150	°C	
Junction Temperature	TJ	+150	°C	
ESD RATINGS				
Human Body Model	НВМ	1500	V	
Charged Device Model	CDM	2000	V	
Machine Model	MM	200	V	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Short circuits from the output to V_{CC} can cause excessive heating and potential destruction. The maximum short circuit current is independent

Table 2. THERMAL INFORMATION (Note 2)

Thermal Metric	Symbol	Limit	Unit
Junction to Ambient – SOIC8	θ_{JA}	238	°C/W

^{2.} Short-circuits can cause excessive heating and destructive dissipation. These values are typical.

Table 3. OPERATING CONDITIONS

Parameter	Symbol	Limit	Unit
Operating Supply Voltage	V _S	2 to 36	V
Specified Operating Range	T _A	-40 to +125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

of the magnitude of V_{CC} .

Table 4. ELECTRICAL CHARACTERISTICS (Vs=+5.0 V, At T_A = +25°C) **Boldface** limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+125^{\circ}C$.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS	-			-	-	-
Offset Voltage	V _{OS}	Vo = 1.4 V, $R_S = 0 \Omega$, $V_S = 5 V$ to		1	5	mV
		30 V, $V_{CM} = 0$ to $V_{CC} - 1.5$ V			9	mV
Input Bias Current	I _{IB}			25	250	nA
					400	nA
Input Offset Current	los			5	50	nA
					150	nA
Input Common Mode Range (Note 3)	V _{ICR}		0		V _{CC} – 1.5	V
			0		V _{CC} - 2	٧
Differential Input Voltage (Note 4)	V_{ID}				V _{CC}	V
OUTPUT CHARACTERISTICS						
Output Voltage Low	V _{OL}	V_{ID} = 1 V, I_O = 4 mA		250	400	mV
		Ī			700	mV
Output Sink Current	I _O	$V_{ID} = -1, V_O = 1.5 V$	6	16		mA
Output Leakage Current	Іон	V _{ID} = 1 V, V _{CC} = V _O = 5 V		0.1		nA
		V _{ID} = 1 V, V _{CC} = V _O = 30 V			1	μΑ
DYNAMIC PERFORMANCE						
Open Loop Voltage Gain	A _{VOL}	V_{CC} = 15 V, R_{PU} = 15 k Ω	94	106		dB
Propagation Delay L-H	t _{PLH}	5 mV overdrive, R_{PU} = 5.1 k Ω		850		ns
		20 mV overdrive, R_{PU} = 5.1 kΩ		490		ns
		100 mV overdrive, R_{PU} = 5.1 k Ω		300		ns
		TTL Input, Vref = +1.4 V, R_{PU} = 5.1 k Ω		220		ns
Propagation Delay H-L	t _{PHL}	5 mV overdrive, R_{PU} = 5.1 k Ω		620		ns
		20 mV overdrive, R_{PU} = 5.1 kΩ		400		ns
		100 mV overdrive, R_{PU} = 5.1 k Ω		250		ns
		TTL Input, Vref = +1.4 V, R_{PU} = 5.1 k Ω		350		ns
POWER SUPPLY						
Quiescent Current	I _{CC}	V _{CC} = 5 V		0.5	_	mA
		V _{CC} = 30 V		0.5	1.25	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{3.} The input common mode voltage of either input signal should not be allowed to go negative by more than 0.3 V. The upper end of the common

mode voltage range is VCC – 1.5 V, but either or both inputs can go to +30 V without damage.
 Positive excursions of the input voltage may exceed the power supply level. As long as the other voltage remains within the common mode range, the comparator will provide a proper output stage. The low input voltage state must not be less than 0.3 V below the negative supply

TYPICAL CHARACTERISTICS

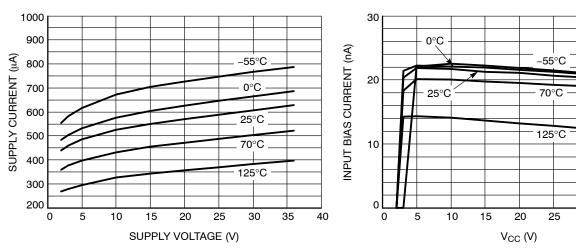


Figure 1. Supply Current vs. Supply Voltage

Figure 2. Input Bias Current vs. V_{CC}

 $V_{IN} = 0 V$

35

40

30

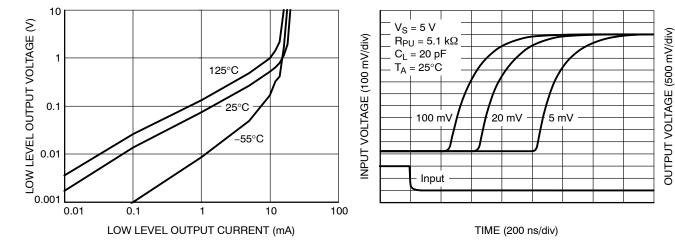


Figure 3. Low Level Output Voltage vs. Output Current

Figure 4. Propagation Delay L-H vs. Overdrive

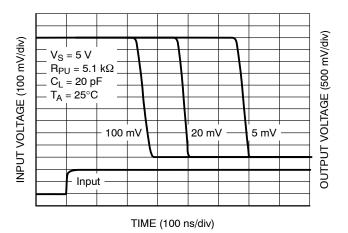
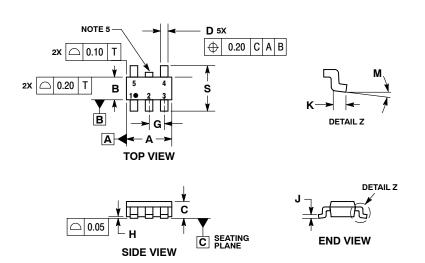


Figure 5. Propagation Delay H-L vs. Overdrive

PACKAGE DIMENSIONS

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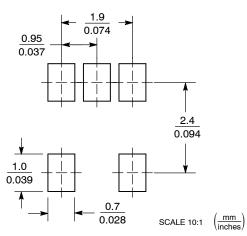


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2
- FROM BODY.

	MILLIMETERS			
DIM	MIN	MAX		
Α	3.00	3.00 BSC		
В	1.50 BSC			
С	0.90	1.10		
D	0.25	0.50		
G	0.95 BSC			
Н	0.01	0.10		
J	0.10	0.26		
K	0.20	0.60		
М	0 °	10°		
S	2.50	3.00		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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